



DMT10H072LFDF

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Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
1001/	$62m\Omega @ V_{GS} = 10V$	4A
100V	80mΩ @ V _{GS} = 6V	3.5A

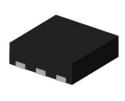
Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

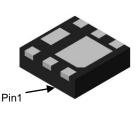
Applications

- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

U-DFN2020-6 (Type F)



Top View



Bottom View

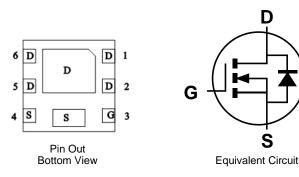


Features and Benefits

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4)
- Weight: 0.0065 grams (Approximate)





7							
	Part Number	Case	Quantity Per Reel				
	DMT10H072LFDF-7	U-DFN2020-6 (Type F)	3,000				
	DMT10H072LFDF-13	U-DFN2020-6 (Type F)	10,000				
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

U-DFN2020-6 (Type F)



 $\begin{array}{l} 72 = \mbox{Product Type Marking Code} \\ \mbox{YM} = \mbox{Date Code Marking} \\ \mbox{Y} = \mbox{Year (ex: G = 2019)} \\ \mbox{M} = \mbox{Month (ex: 9 = September)} \end{array}$

Date Code Key			_									
Year	2019	20)20	2021	2022	20	023	2024	2025	20	026	2027
Code	G		Н		J		K	L	М		Ν	0
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

U-DFN2020-6 (Type F)



72 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 9 = 2019) W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key									
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027
Code	9	0	1	2	3	4	5	6	7
Week	1-26			27-52			53		
Code	A-Z			a-z			Z		
Internal Code	Sun	Mon		Tue	Wed	Thu		Fri	Sat
Code	Т	U		V	W	Х		Y	7



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 6)	T _A = +25°C T _A = +70°C	ID	4 3.2	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	·	I _{DM}	22	А
Maximum Body Diode Continuous Current		ls	1.6	А
Avalanche Current, L = 0.1mH (Note 9)	I _{AS}	6	А	
Avalanche Energy, L = 0.1mH (Note 9)		E _{AS}	1.8	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Dower Dissinction (Note 5)	T _A = +25°C	D	0.8	10/
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ extsf{ heta}JA}$	149	°C/W
Total Dower Dissinction (Note 6)	T _A = +25°C		1.8	W
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.1	
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	71	°C/W
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	13	C/VV	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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Characteristic OFF CHARACTERISTICS (Note 7)	Symbol	Min	Тур	Max	Unit	Test Condition
	D) (100	1		M	
Drain-Source Breakdown Voltage	BV _{DSS}	100	—		V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{\rm DS} = 80 \text{V}, V_{\rm GS} = 0 \text{V}$
Gate-Source Leakage	I _{GSS}	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)			1			
Gate Threshold Voltage	V _{GS(TH)}	1	—	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
		-	47	62	mΩ	$V_{GS} = 10V, I_D = 4.5A$
Static Drain-Source On-Resistance	R _{DS(ON)}		54	80	11152	$V_{GS} = 6V, I_D = 4A$
			64	110	mΩ	$V_{GS} = 4.5V, I_D = 2.6A$
Diode Forward Voltage	V _{SD}		0.7	1.0	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		228	_	pF	
Output Capacitance	Coss	_	89.3	_	pF	V _{DS} = 50V, V _{GS} = 0V, f = 1MHz
Reverse Transfer Capacitance	Crss	_	2.5	—	pF	
Gate Resistance	Rg	_	8.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	2.5	_	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	4.5	—	nC	
Gate-Source Charge	Q _{gs}	_	0.6	—	nC	$V_{DS} = 50V, I_D = 4.5A$
Gate-Drain Charge	Q _{gd}	_	1.3	_	nC	
Turn-On Delay Time	t _{D(ON)}	—	3.0	—	ns	
Turn-On Rise Time	t _R		3.1	_	ns	$V_{DS} = 50V, R_{L} = 11\Omega$
Turn-Off Delay Time	t _{D(OFF)}		12.3	_	ns	$V_{GS} = 10V, R_{GEN} = 3\Omega$
Turn-Off Fall Time	t _F		4.3	_	ns	
Reverse Recovery Time	t _{RR}		22.9	_	ns	
Reverse Recovery Charge	Q _{RR}		45.2	_	nC	I _F = 4.5A, di/dt = 300A/µs

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

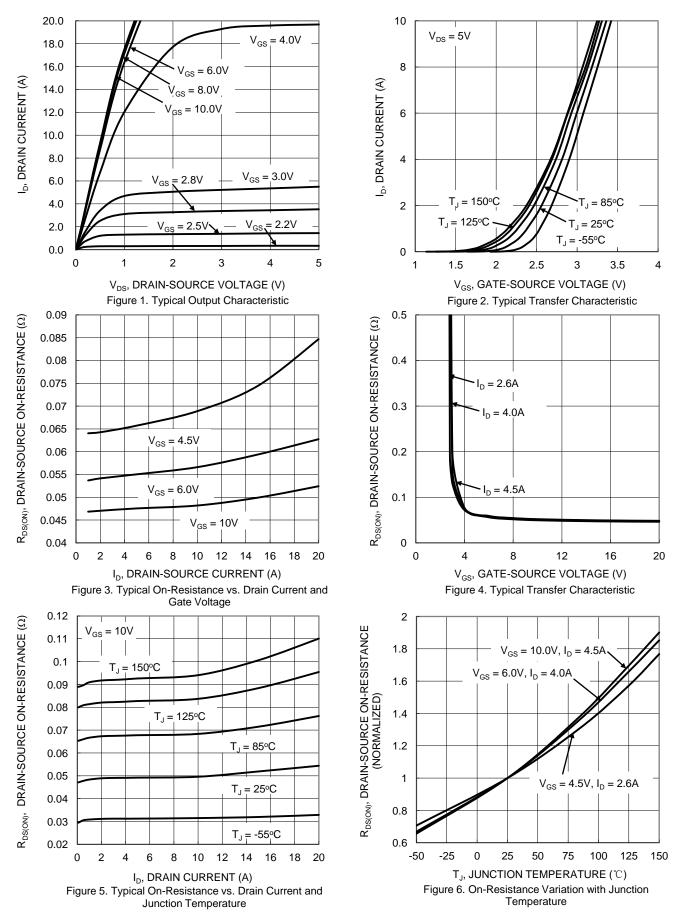
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

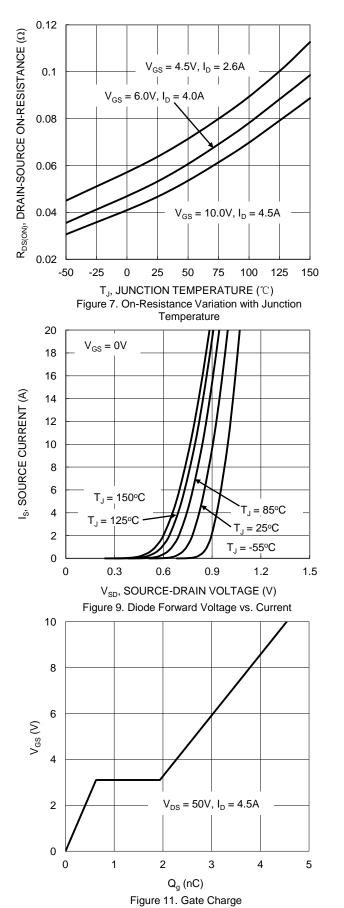


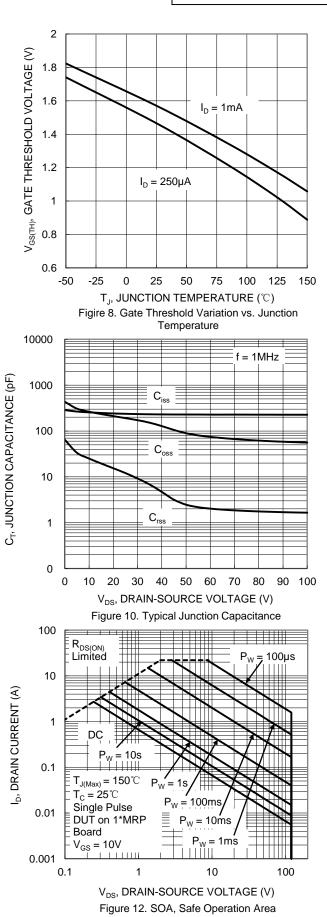
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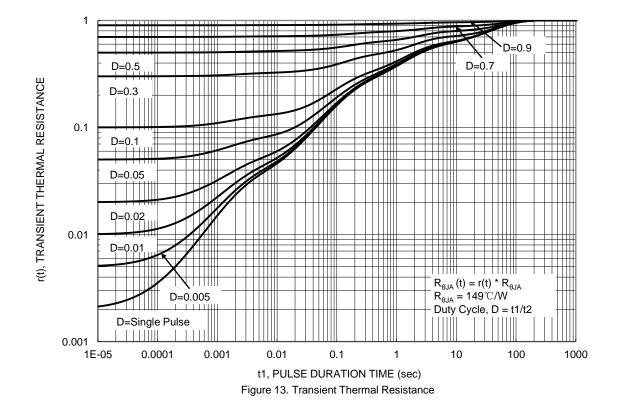
DMT10H072LFDF Datasheet number: DS38574 Rev. 5 - 2









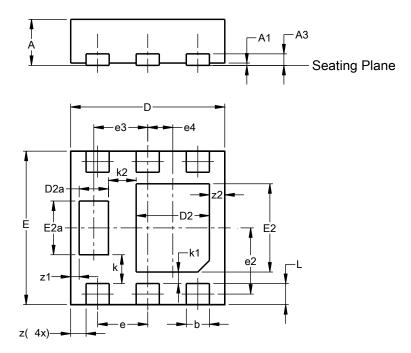




Package Outline Dimension

Please see http://www.diodes.com/package-outlines.html for the latest version.

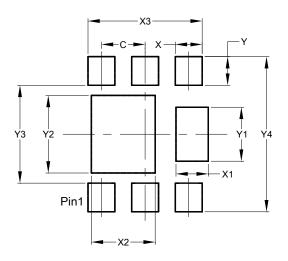
U-DFN2020-6 (Type F)



U-DFN2020-6									
	(Type F)								
Dim	Min	Max	Тур						
Α	0.57	0.63	0.60						
A1	0.00	0.05	0.03						
A3	-	-	0.15						
b	0.25	0.35	0.30						
D	1.95	2.05	2.00						
D2	0.85	1.05	0.95						
D2a	0.33	0.43	0.38						
Е	1.95	2.05	2.00						
E2	1.05	1.25	1.15						
E2a	0.65	0.75	0.70						
е	0.65 BSC								
e2	C).863 BS	SC						
e3		0.70 BS	С						
e4	C).325 BS	SC						
k		0.37 BS	С						
k1		0.15 BS	С						
k2		0.36 BS	С						
L	0.225	0.325	0.275						
z		0.20 BS	С						
z1	C).110 BS	SC						
z2		0.20 BS	С						
All C	Dimens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 (Type F)

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Dimensions	Value
Dimensions	(in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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